

INVENTOR INFORMATION

10/555855

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APPLICATION INFORMATION

Title Line One:: THERMOELECTRIC SEMICONDUCTOR MATERIAL, T
Title Line Two:: HERMOELECTRIC SEMICONDUCTOR ELEMENT USIN
Title Line Three:: G THERMOELECTRIC SEMICONDUCTOR MATERIAL,
Title Line Four:: THERMOELECTRIC MODULE USING THERMOELECT
Title Line Five:: RIC SEMICONDUCTOR ELEMENT AND MANUFACTUR
Title Line Six:: ING METHOD FOR SAME
Total Drawing Sheets:: 19
Formal Drawings?: Yes
Application Type:: Utility
Docket Number:: P/2850-120
Secrecy Order in Parent Appl.?: No

CONTINUITY INFORMATION

This application is a:: 371 OF
> Application One:: PCT/JP04/006493
Filing Date:: 05-07-2004

PRIOR FOREIGN APPLICATIONS

Foreign Application One:: P2003-130618
Filing Date:: 05-08-2003
Country:: Japan
Priority Claimed:: Yes

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